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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/612,414	07/02/2003	Yoshio Kurosawa	1324.68134	3620 ·
Patrick G. Burns, Esq. GREER, BURNS & CRAIN, LTD. 300 South Wacker Dr., Suite 2500			EXAMINER ERDEM, FAZLI	
Patrick G. Burns, Esq. GREER, BURNS & CRAIN, LTD. 300 South Wacker Dr., Suite 2500	•			
300 South Wack Chicago, IL 606				PAPER NUMBER
Cincago, IL 000			2826	
SHORTENED STATUTORY	Y PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE	
3 MON	VTHS	01/10/2007	PAI	PER

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

t :	Application No.	Applicant(s)	
	10/612,414	KUROSAWA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Fazli Erdem	2826	
The MAILING DATE of this comm Period for Reply	unication appears on the cover she	eet with the correspondence address	
A SHORTENED STATUTORY PERIOD WHICHEVER IS LONGER, FROM THE - Extensions of time may be available under the provisi after SIX (6) MONTHS from the mailing date of this co. If NO period for reply is specified above, the maximum - Failure to reply within the set or extended period for reany reply received by the Office later than three month earned patent term adjustment. See 37 CFR 1.704(b)	MAILING DATE OF THIS COMN ons of 37 CFR 1.136(a). In no event, however, remunication. In statutory period will apply and will expire SIX (6 ply will, by statute, cause the application to become after the mailing date of this communication, on the statute of the communication, or the statute of the statute of the communication, or the statute of the	IUNICATION. may a reply be timely filed S) MONTHS from the mailing date of this communication. me ABANDONED (35 U.S.C. § 133).	
Status			
 Responsive to communication(s) This action is FINAL. Since this application is in condition closed in accordance with the practice. 	2b)⊠ This action is non-final. on for allowance except for formal	• •	
Disposition of Claims			
4) Claim(s) 5-8 is/are pending in the 4a) Of the above claim(s) is 5) Claim(s) 7 and 8 is/are allowed. 6) Claim(s) 5 and 6 is/are rejected. 7) Claim(s) is/are objected to 8) Claim(s) are subject to resi	/are withdrawn from consideration		
·· _	the Cassines		•
9) The specification is objected to by 10) The drawing(s) filed on is/a Applicant may not request that any of Replacement drawing sheet(s) includ 11) The oath or declaration is objected.	re: a) accepted or b) objecte bjection to the drawing(s) be held in all ing the correction is required if the dra	peyance. See 37 CFR 1.85(a). awing(s) is objected to. See 37 CFR 1.121(d)) .
Priority under 35 U.S.C. § 119		•	
12) Acknowledgment is made of a clair a) All b) Some * c) None of 1. Certified copies of the prior 2. Certified copies of the prior 3. Copies of the certified copies	ty documents have been received ty documents have been received es of the priority documents have l tional Bureau (PCT Rule 17.2(a)).	I. I in Application No Deen received in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review 3) Information Disclosure Statement(s) (PTO/SB/06) Paper No(s)/Mail Date	(PTO-948) Pape	view Summary (PTO-413) or No(s)/Mail Date se of Informal Patent Application or:	

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DETAILED ACTION

A certified translation of the priority document for the current application was filed. Therefore, Satou prior art that was used in making the final rejection cannot be used anymore. Hence, the final rejection issued on 10/23/2006 has been withdrawn. However, after further search and consideration this action is issued and made non-final.

Allowable Subject Matter

1. Claims 7 and 8 allowed.

DETAILED ACTION

Allowable Subject Matter

2. Claims 7 and 8 allowed.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 5 and 6 rejected under 35 U.S.C. 103(a) as being unpatentable over Yamazaki et al. (6,603,453) in view of further in view of Yamazaki et al. (2001/0052950) further in view of further in view of Matsumoto (5,396,084)

Regarding Claims 5 and 6, Yamazaki et al. ('453) disclose a semiconductor device and method for manufacturing the same where in Fig. 1, a P channel TFT and an N channel TFT are disclosed on a substrate 801. Furthermore, P channel TFT has a fires gate insulation film 805, a second gate insulating film 808, gate electrode 813 on the second

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gate insulation film. N channel TFT also has a first gate insulation film and a gate electrode 814 disposed on the second gate insulation film 809. Yamazaki et al. fail to disclose the required gate insulating layer over semiconductor layer, the required lightly doped regions and the required gate electrode between gate insulating layers and the required configuration of the first and second gate insulating films. However, Yamazaki et al. ('950) disclose s semiconductor display device and manufacturing method thereof where in claims 1, 2, 3, 16 and 19 the required gate insulating layer over semiconductor layer and the required lightly doped regions are disclosed. Matsumoto disclose a thin film transistor device having driving circuit and matrix circuit where in Fig. 1, second gate electrode 16 is located between the first gate insulating layer 14 and the second gate insulating layer 19.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required insulating layer over semiconductor layer with lightly doped regions and the required gate electrode between gate insulating films and the required configuration of the first and the second gate insulating films in Yamazaki et al. as taught by Yamazaki et al. ('950) et al and Matsumoto, respectively, in order to have a liquid crystal panel display device with flexibility in terms of insulating film thickness and locations.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

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supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

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like assistance from a USPTO Customer Service Representative or access to the automated

information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

FE

January 7, 2007

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